

## **ELECTRICAL CHARACTERISTICS** (Ambient Temperature = 25°C unless otherwise specified)

#### **INPUT**

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Forward Voltage	$V_{\rm F}$	$I_F = 10 \text{mA}$		1.2	1.4	V
Reverse Leakage Current		$V_R = 4V$			10	μΑ
Terminal Capacitance	$C_{t}$	V = 0V, $f = 1KHz$		30	250	pF

#### **OUTPUT**

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector-Emitter Break- down Voltage	$\mathrm{BV}_{\mathrm{CEO}}$	$I_C = 0.1 \text{mA}, I_F = 0 \text{mA}$	300			V
Emitter-Collector Break- down Voltage	$\mathrm{BV}_{\mathrm{ECO}}$	$I_E = 0.01 \text{mA}, I_F = 0 \text{mA}$	0.1			V
Collector-Emitter Dark Current	$I_{CEO}$	$V_{CE} = 200V, I_F = 0mA$			200	nA

#### **COUPLED**

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Current transfer ratio	CTR	$I_F = 1 \text{mA}, V_{CE} = 2V$	1000	4000		%
Collector—Emitter Saturation Voltage (1)	V <sub>CE(sat)</sub>	$I_F = 20 \text{mA}, I_C = 100 \text{mA}$			1.2	V
Input to Output Isolation Voltage	$ m V_{ISO}$	See Note 1	5000			$V_{RMS}$
Input to Output Isolation Resistance	$R_{\rm ISO}$	V <sub>IO</sub> = 500V See Note 1	5x10 <sup>10</sup>			Ω
Floating Capacitance	$C_{\mathrm{f}}$	V = 0V, $f = 1MHz$		0.6	1	pF
Output Rise Time	t <sub>r</sub>	$V_{CE} = 2V$ , Ic = 20mA, $R_{L} = 100\Omega$		100		μs
Output Fall Time	$t_{\mathrm{f}}$	v <sub>CE</sub> - 2 v, 1c - 20mA, K <sub>L</sub> - 10082		20		μs

Note 1: Measure with input leads shorted together and output leads shorted together.



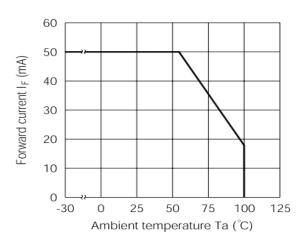


Fig 1 Forward Current vs TA

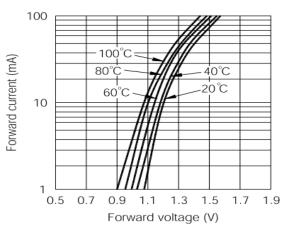


Fig 3 Forward Current vs Forward Voltage

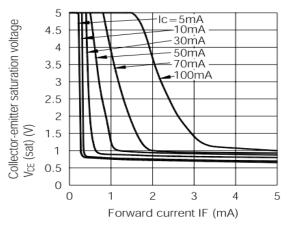


Fig 5 Collector-emitter Saturation Voltage vs Forward Current

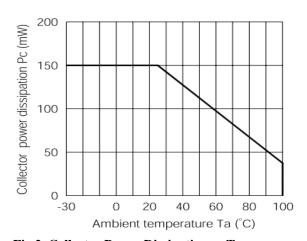


Fig 2 Collector Power Dissipation vs  $T_A$ 

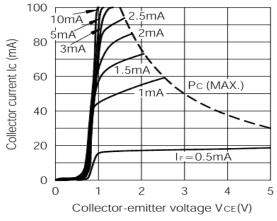


Fig 4 Collector Current vs Collector-Emitter Voltage

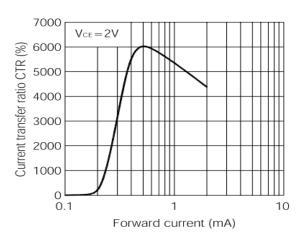


Fig 6 Current Transfer Ratio vs Forward Current



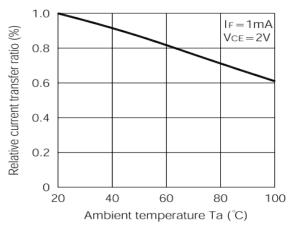


Fig 7 Relative CTR vs T<sub>A</sub>

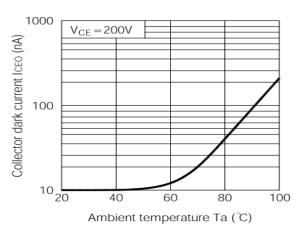


Fig 9 Collector Dark Current vs TA

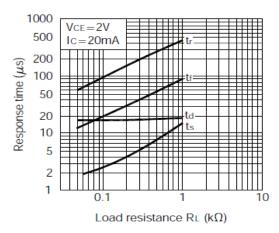


Fig 11 Response Time vs Load Resistance

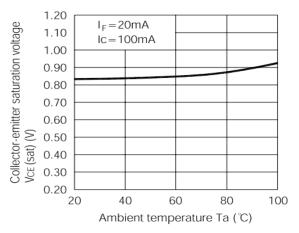


Fig 8 Collector-Emitter Saturation Voltage vs  $T_A$ 

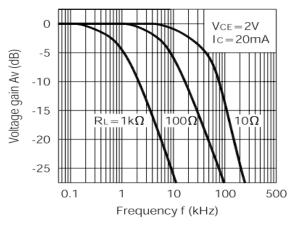
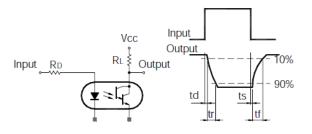
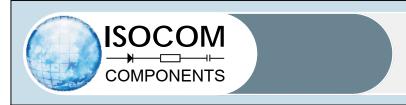


Fig 10 Frequency Response



**Response Time Test Circuit** 



#### **ORDER INFORMATION**

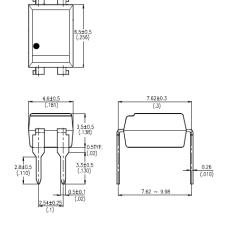
IS7000 (UL Approval)				
After PN	PN	Description	Packing quantity	
None	IS7000	Standard DIP 4	100 pcs per reel	
G	IS7000G	10mm Lead Spacing	100 pcs per tube	
SM	IS7000SM	Surface Mount	100 pcs per tube	
SMT&R	IS7000SMT&R	Surface Mount Tape & Reel	1000 pcs per reel	

IS7000X (UL and VDE Approval)				
After PN	PN	Description	Packing quantity	
None	IS7000X	Standard DIP 4	100 pcs per reel	
G	IS7000XG	10mm Lead Spacing	100 pcs per tube	
SM	IS7000XSM	Surface Mount	100 pcs per tube	
SMT&R	IS7000XSMT&R	Surface Mount Tape & Reel	1000 pcs per reel	

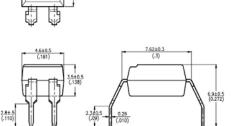


## **PACKAGE DIMENSIONS (mm)**

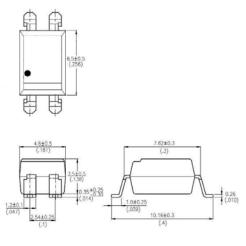
DIP



**G** Form

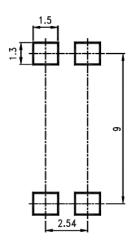


**SMD** 

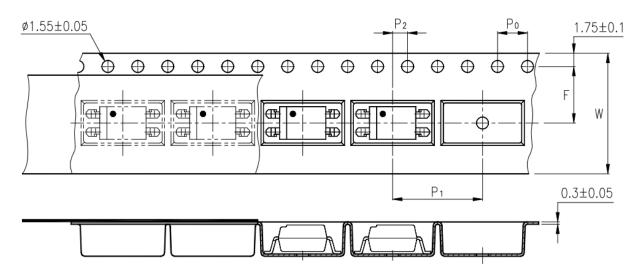




## RECOMMENDED SOLDER PAD LAYOUT FOR SMD (mm)



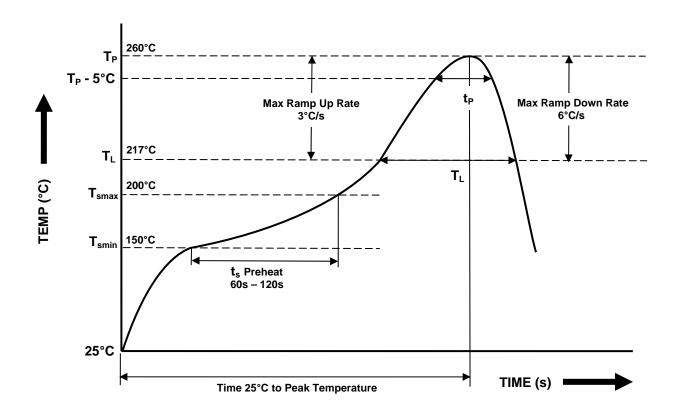
## **TAPE AND REEL PACKAGING (mm)**



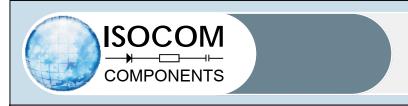
Description	Symbol	Dimensions in mm (inches)
Tape wide	W	$16 \pm 0.3  (.63)$
Pitch of sprocket holes	P <sub>0</sub>	4 ± 0.1 ( .15 )
Distance of commentment	F	$7.5 \pm 0.1 ( .295 )$
Distance of compartment	P <sub>2</sub>	$2 \pm 0.1 (.079)$
Distance of compartment to compartment	P <sub>1</sub>	12 ± 0.1 ( .472 )



# IR REFLOW SOLDERING TEMPERATURE PROFILE (One Time Reflow Soldering is Recommended)

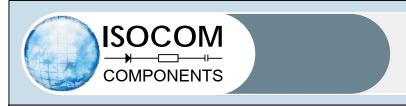


Profile Details	Conditions
Preheat - Min Temperature (T <sub>SMIN</sub> ) - Max Temperature (T <sub>SMAX</sub> ) - Time T <sub>SMIN</sub> to T <sub>SMAX</sub> (t <sub>s</sub> )	150°C 200°C 60s - 120s
$\begin{tabular}{lll} \textbf{Soldering Zone} \\ - & \mbox{Peak Temperature } (T_P) \\ - & \mbox{Liquidous Temperature } (T_L) \\ - & \mbox{Time within } 5^{\circ}\mbox{C of Actual Peak Temperature } (T_P - 5^{\circ}\mbox{C}) \\ - & \mbox{Time maintained above } T_L \ (t_L) \\ - & \mbox{Ramp Up Rate } (T_L \ \mbox{to } T_P) \\ - & \mbox{Ramp Down Rate } (T_P \ \mbox{to } T_L) \\ \end{tabular}$	260°C 217°C 30s 60s 3°C/s max 6°C/s max
Average Ramp Up Rate (T <sub>smax</sub> to T <sub>P</sub> )	3°C/s max
Time 25°C to Peak Temperature	8 minutes max



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